

IPP21N03L G

Request a Quote

IPP21N03L G Information

	Part Number	IPP21N03L G	
-	Manufacturer	Infineon Technologies	
www.heiseper.com	Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single	
	Description	MOSFET N-CH TO-220	
1	Package	TO-220-3	
-		For the pricing/inventory/lead time, please contact us	
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com	

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IPP21N03L G Specifications

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Manufacturer Part Number	IPP21N03L G
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	ТО-220-3
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	-
Current - Continuous Drain (Id) @ 25°C	-
Drive Voltage (Max Rds On, Min Rds On)	-
Vgs(th) (Max) @ Id	-
Gate Charge (Qg) (Max) @ Vgs	-
Input Capacitance (Ciss) (Max) @ Vds	-
Vgs (Max)	-
FET Feature	-
Power Dissipation (Max)	-
Rds On (Max) @ Id, Vgs	-
Operating Temperature	-
Mounting Type	Through Hole
Supplier Device Package	PG-TO-220-3
Package / Case	ТО-220-3
	Report errors?

IPP21N03L G Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IPP21N03L G Payment Methods



IPP21N03L G Shipping Methods



If you have any question about IPP21N03L G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com